

## **Electronic Supplementary Information (ESI)**

# **Aggregation-induced emission (AIE) active iridium(III) complex toward highly efficient single-layer non-doped electroluminescent device**

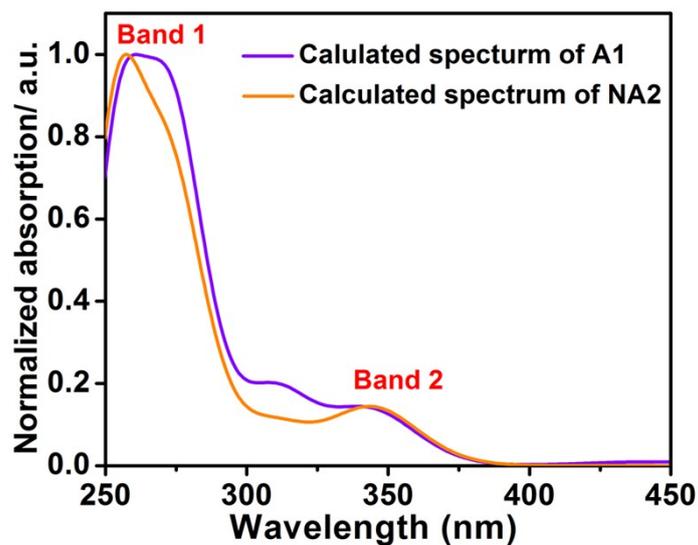
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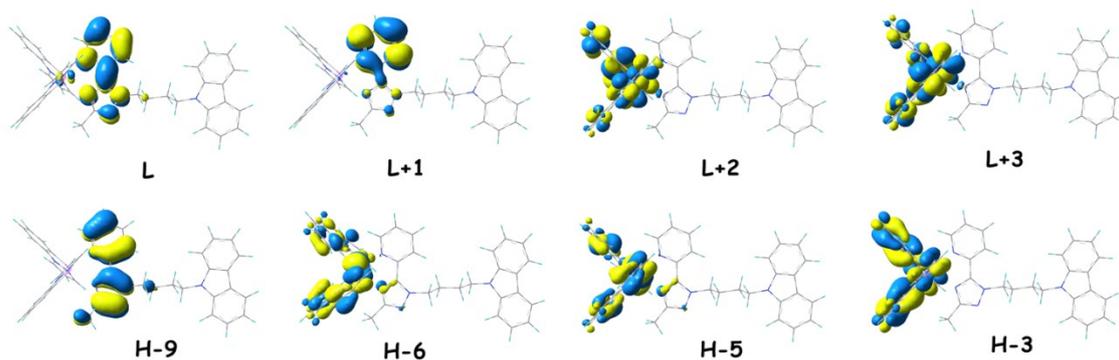


**Fig. S1.** TD-DFT simulated absorption spectra of **A1** and **NA2** in  $\text{CH}_3\text{CN}$ .

**Table S1.** Calculated excited energies, dominant orbital excitations, and oscillator strengths ( $f$ ) of **A1** in  $\text{CH}_3\text{CN}$  solution obtained from TD-DFT calculation.

<b>A1</b>	Excited state	eV/nm	$f$	Major contributions <sup>a</sup>	Character <sup>b</sup>
Band 1	S35	4.86/255	0.38	H-6→L+3 (17%)	IL
				H-5→L+2 (15%)	IL
				H-3→L+3 (19%)	IL
Band 1	S26	4.56/272	0.21	H-9→L (38%)	IL
				H-6→L+1 (30%)	IL/MLCT/LLCT
				H-5→L+1 (15%)	IL/MLCT/LLCT
Band 2	S6	3.61/344	0.08	H-6→L (92%)	MLCT/LLCT

<sup>a</sup> H and L denote HOMO and LUMO, respectively. <sup>b</sup> MLCT, LLCT and IL denote metal-to-ligand charge transfer, ligand-to-ligand and ligand centered charge transfer, respectively.

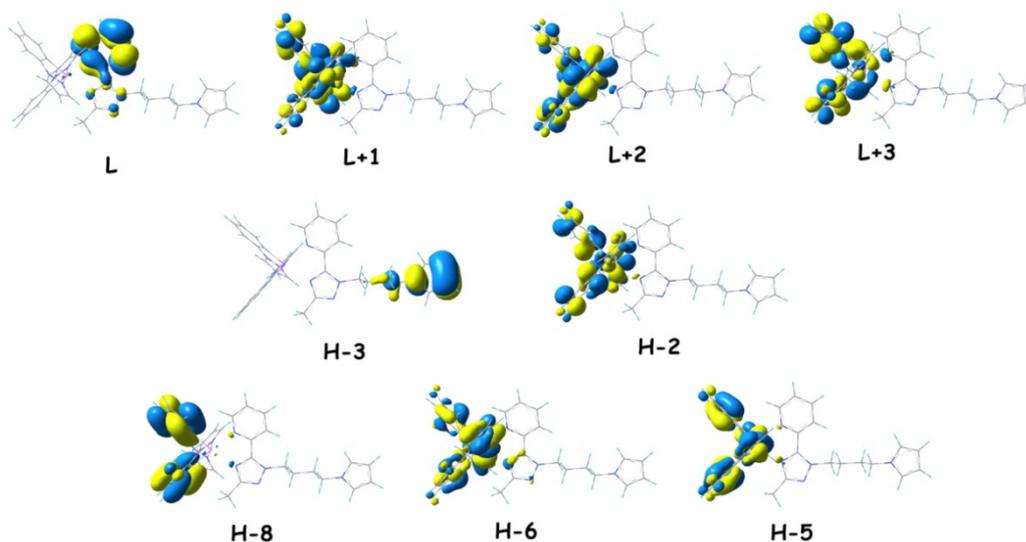


**Fig. S2.** Selected frontier molecular orbitals involved in crucial electronic excitations of **NA1**. H and L denote HOMO and LUMO, respectively.

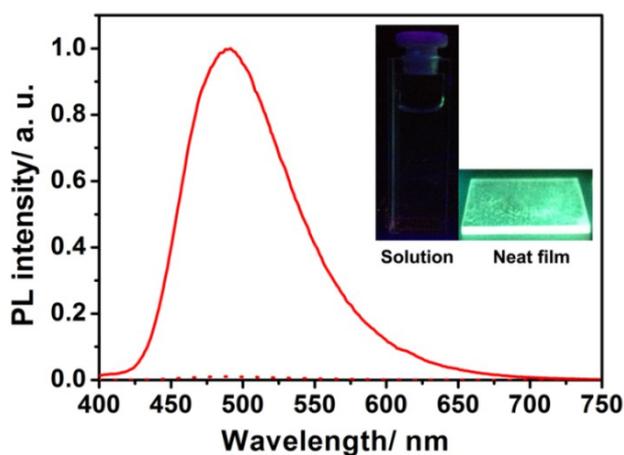
**Table S2.** Calculated excited energies, dominant orbital excitations, and oscillator strength ( $f$ ) of **NA2** in  $\text{CH}_3\text{CN}$  solution obtained from TD-DFT calculation.

<b>NA2</b>	Excited state	eV/nm	$f$	Major contributions <sup>a</sup>	Character <sup>b</sup>
Band 1	S30	4.86/255	0.37	H-6→L+3 (16%)	IL
				H-5→L+2 (16%)	IL
				H-3→L+3 (18%)	IL/MLCT/LLCT
Band 2	S5	3.59/345	0.07	H-8→L (38%)	LLCT
				H-6→L+1 (31%)	IL
				H-2→L (44%)	MLCT/LLCT

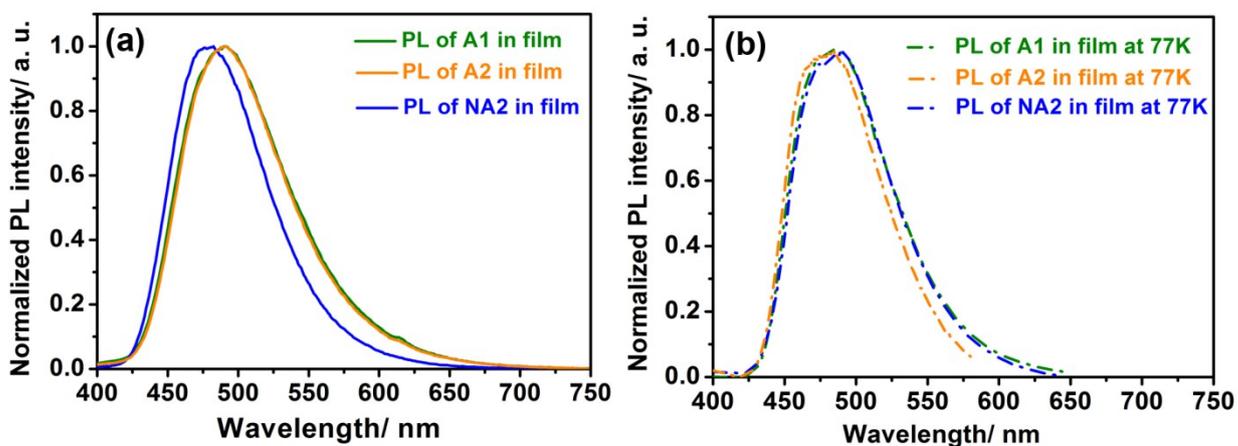
<sup>a</sup>H and L denote HOMO and LUMO, respectively. <sup>b</sup>MLCT, LLCT and IL denote metal-to-ligand charge transfer, ligand-to-ligand and ligand centered charge transfer, respectively.



**Fig. S3.** Selected frontier molecular orbitals involved in crucial electronic excitations of NA2. H and L denote HOMO and LUMO, respectively.



**Fig. S4.** Emission spectra of A2 in CH<sub>3</sub>CN solution and in neat film.



**Fig. S5.** Emission spectra of complexes A1, A2 and NA2 in neat film at room temperatures (a) and 77 K (b).

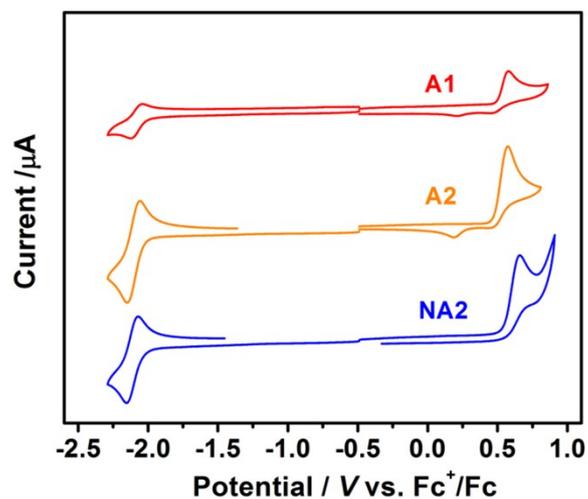


Fig. S6. CV curves of A1, A2 and NA2.

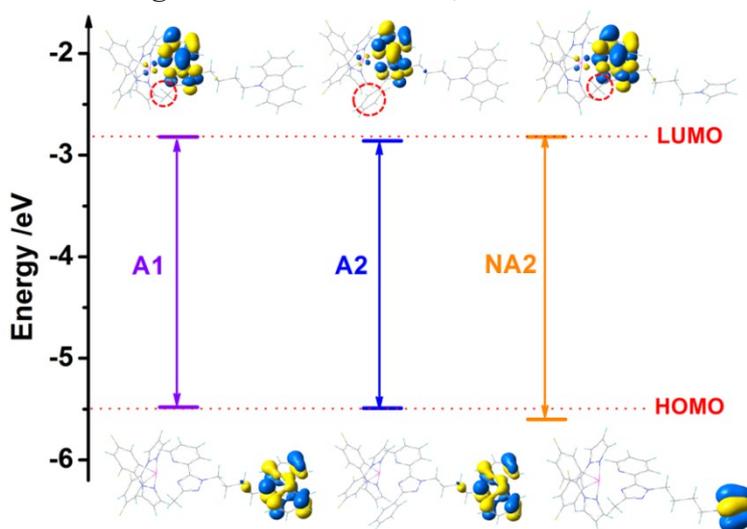


Fig. S7. HOMOs and LUMOs of A1, A2 and NA2 calculated by DFT method.

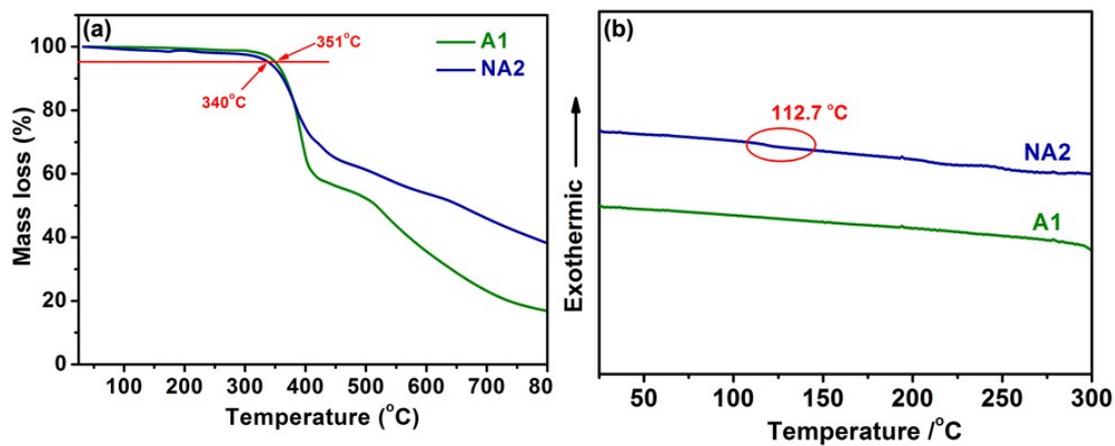


Fig. S8. TGA (a) and DSC (b) curves of the iridium(III) complexes of A1 and NA2.

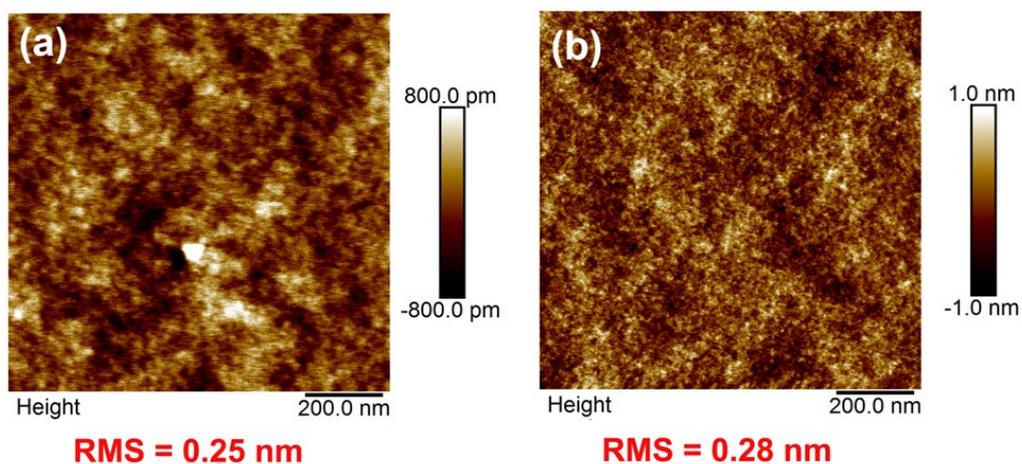


Fig. S9. AFM topographic images of the solution-processed films of A1 (a) and NA2 (b).

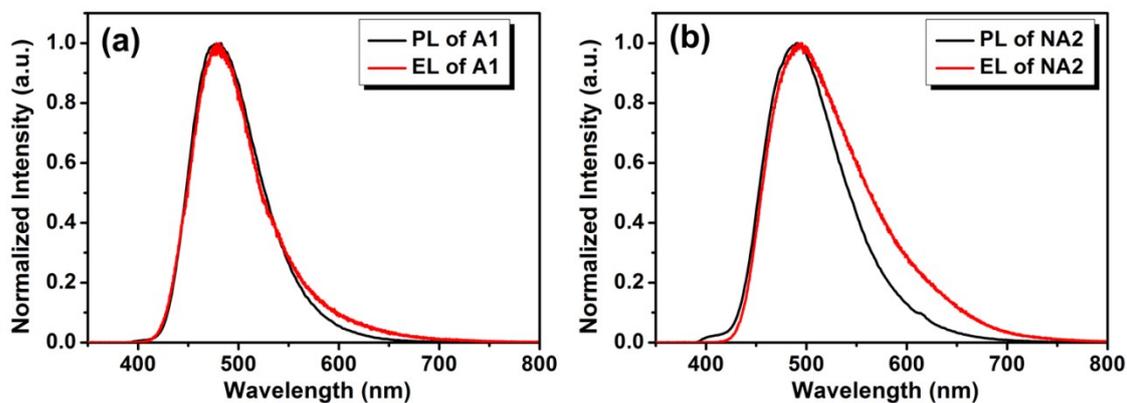


Fig.S10. PL spectra in neat films and EL spectra of A1 (a) and NA2 (b)

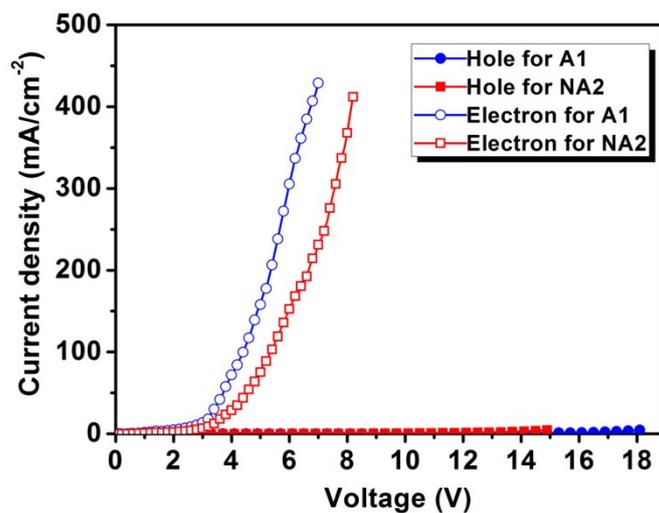


Fig. S11. Current density-Voltage (J-V) of the hole-only and electron-only devices based complexes A1 and NA2.

**Table S3** Vertical ionization potential (IP), vertical electron affinity (EA), extraction potential (HEP and EEP) and intramolecular reorganization energy ( $\lambda_{\text{hole}}$  and  $\lambda_{\text{electron}}$ ).

	IP (v)	HEP (v)	EA (v)	EEP (v)	$\lambda_{\text{hole}}$	$\lambda_{\text{electron}}$
<b>A1</b>	8.47	8.30	4.24	3.77	0.17	0.47
<b>NA2</b>	8.92	8.68	4.24	3.78	0.24	0.46